March 1998

Quad Gated Non-Inverting Power Driver

Features

- Four 600mA Non-Inverting Power Output Drivers
- 50V and 1A Maximum Rated Power Output Drivers
- V_{CE(SUS)} Capability35V
- Inputs Compatible With TTL or 5V CMOS Logic
- · Suitable For Resistive, Lamp or Inductive Loads
- Inductive Clamps on Each Output
- · High Dissipation Power-Frame Package
- Operating Temperature Ranges -40°C to 105°C

Applications

- Solenoids
- Relays
- Lamps
- Steppers
- Small Motors
- Displays

System Applications

- Automotive
- Appliances
- Industrial Controls
- Robotics

Description

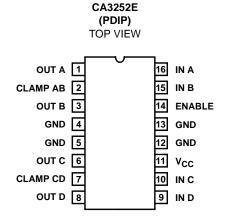
The CA3252 is used to interface low-level logic to high current loads. Each Power Driver has four inverting switches consisting of an inverting logic input stage and an inverting low-side driver output stage. All inputs are 5V TTL/CMOS logic compatible and have a common Enable input. On-chip steering diodes are connected from each output (in pairs) to the CLAMP pins (in pairs) which may be used in conjunction with external zener diodes to protect the IC against over-voltage transients that result from inductive load switching. The CA3252 may be used in a variety of automotive and industrial control applications to drive relays, solenoids, lamps and small motors.

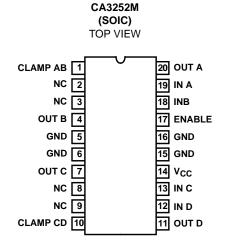
To allow for maximum heat transfer from the chip, all ground pins on the DIP and SOIC packages are directly connected to the mounting pad of the chip. Integral heat spreading lead frames directly connect the bond pad and ground leads for good heat dissipation. In a typical application, the package is mounted on a copper PC Board. By increasing copper ground area on the PC Board, more heat is conducted away from the ground leads. The junction-to-ambient thermal resistances may be reduced to less than 40°C/W with approximately two square inches of copper area.

Ordering Information

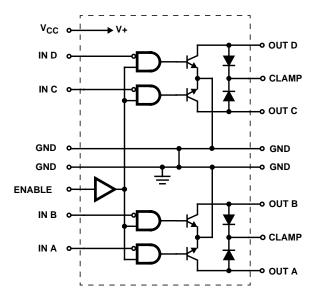
PART NUMBER	TEMP. (°C)	PACKAGE	PKG. NO.
CA3252E	-40 to 105	16 Ld PDIP	E16.3
CA3252M	-40 to 105	20 Ld SOIC	M20.3

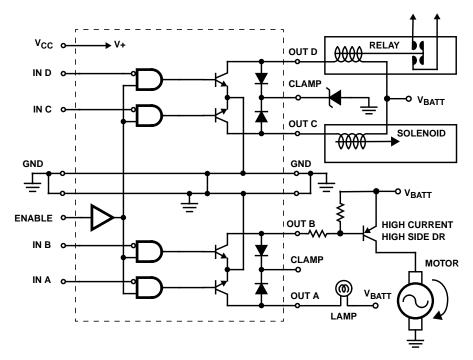
Pinouts





Functional Block Diagram





TRUTH TABLE (Each Output)

ENABLE	IN	OUT
Н	L	L
Н	Н	Н
L	Х	Н

H = High, L = Low, X = Don't Care

FIGURE 1. CA3252 QUAD NON-INVERTING POWER DRIVER SHOWN WITH TYPICAL APPLICATION LOADS

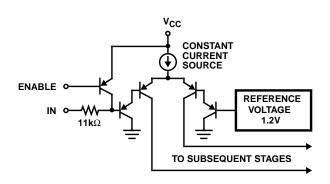


FIGURE 2. SCHEMATIC OF ONE INPUT SECTION

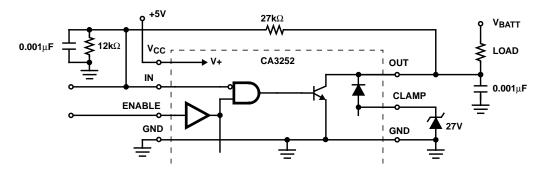


FIGURE 3. TYPICAL LATCHED ON CIRCUIT SWITCHING CONFIGURATION. WHEN V_{IN} IS SWITCHED LOW, THE OUTPUT IS TURNED ON (LOW).

CA3252

Absolute Maximum Ratings

Thermal Information

Thermal Resistance (Typical, Note 2)	θ _{JA} °C/W
CA3252E	45
CA3252M	54
Maximum Junction Temperature	
Maximum Storage Temperature Range	65°C to 150°C
Maximum Lead Temperature Soldering (10s Max).	300°C
(SOIC - Lead Tips Only)	

Operating Conditions

CAUTION: Stresses above those listed in "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress only rating and operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied.

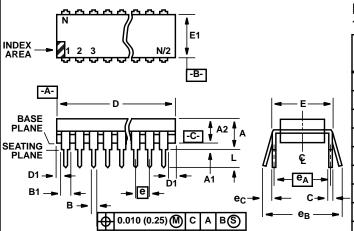
NOTES:

- 1. The Maximum Ambient Temperature is limited for the sustained conditions of the I_{CC(ON)} Supply Current test with all Outputs ON. The total DC current for the CA3252 with all 4 outputs ON should not exceed 0.7A at each output for a total of (4 X 0.7A + Max. I_{CC}) ~ 2.9A. This level of sustained current will significantly increase the on-chip temperature due to increased dissipation. Under any condition, the Absolute Maximum Junction Temperature must not exceed150°C. While any one loaded output may exceed 0.7A, the maximum rating limit is 1A.
- 2. θ_{JA} is measured with the component mounted on an evaluation PC board in free air.

Electrical Specifications $T_A = -40^{\circ}\text{C}$ to 105°C , $V_{CC} = V_{EN} = 5\text{V}$; Unless Otherwise Specified

PARAMETER	SYMBOL	TEST CONDITIONS	MIN	MAX	UNITS
Output Sustaining Voltage	V _{CE(SUS)}	$I_C = 100$ mA, $V_{IN} = 2$ V, $V_{EN} = 2$ V	35	-	V
Output Leakage Current	I _{CEX}	V _{CE} = 50V, V _{IN} = 2V, V _{EN} = 0.8V	-	100	μΑ
Collector to Emitter Saturation Voltage	V _{CE(SAT)}	I _C = 100mA, V _{IN} = 0.8V	-	0.3	V
		I _C = 300mA, V _{IN} = 0.8V	-	0.5	V
		I _C = 600mA, V _{IN} = 0.8V	-	0.8	V
Input Low Voltage	V _{IL}		-	0.8	٧
Input Low Current	I _{IL}	V _{IN} = 0.4V	-15	10	μΑ
Input High Voltage	V _{IH}	I _C = 600mA	2	-	V
Input High Current	lін	I _C = 600mA, V _{IN} = 4.5V	-10	-10	μΑ
Logic Supply Current, All Outputs ON	I _{CC(ON)}	I _C = 600mA, All Outputs ON (Note 1)	-	90	mA
Logic Supply Current, All Outputs OFF	I _{CC(OFF)}	All Outputs OFF	-	10	mA
Clamp Diode Leakage Current	I _R	V _R = 50V (Diode Reverse Voltage)	-	100	μΑ
Clamp Diode Forward Voltage	V _F	I _F = 0.6A	-	1.8	V
		I _F = 1.2A	-	2.0	V
Output Current	Гоит	V_{IN} = 0.4V, V_{BATT} = +13V, Output Load = 10 Ω	0.9	-	А
Turn-ON Propagation Delay Time	t _{PHL}	I _C = 600mA	-	10	μs
Turn-OFF Propagation Delay Time	^t PLH	I _C = 600mA	-	10	μs
Low Enable Voltage	V _{ENL}		-	0.8	V
Low Enable Current	I _{ENL}	V _{EN} = 0.4V	-15	10	μΑ
High Enable Voltage	V _{ENH}		2.0	-	٧
High Enable Current	I _{ENH}	$V_{EN} \ge 2V$	-250	+250	μА

Dual-In-Line Plastic Packages (PDIP)



NOTES:

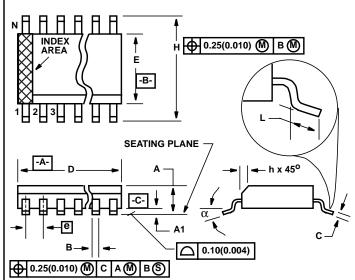
- Controlling Dimensions: INCH. In case of conflict between English and Metric dimensions, the inch dimensions control.
- 2. Dimensioning and tolerancing per ANSI Y14.5M-1982.
- 3. Symbols are defined in the "MO Series Symbol List" in Section 2.2 of Publication No. 95.
- 4. Dimensions A, A1 and L are measured with the package seated in JEDEC seating plane gauge GS-3.
- D, D1, and E1 dimensions do not include mold flash or protrusions. Mold flash or protrusions shall not exceed 0.010 inch (0.25mm).
- E and e_A are measured with the leads constrained to be perpendicular to datum -C-.
- 7. e_B and e_C are measured at the lead tips with the leads unconstrained. e_C must be zero or greater.
- 8. B1 maximum dimensions do not include dambar protrusions. Dambar protrusions shall not exceed 0.010 inch (0.25mm).
- 9. N is the maximum number of terminal positions.
- Corner leads (1, N, N/2 and N/2 + 1) for E8.3, E16.3, E18.3, E28.3, E42.6 will have a B1 dimension of 0.030 - 0.045 inch (0.76 - 1.14mm).

E16.3 (JEDEC MS-001-BB ISSUE D)
16 LEAD DUAL-IN-LINE PLASTIC PACKAGE

INCHES			MILLIM		
SYMBOL	MIN	MAX	MIN	MAX	NOTES
Α	-	0.210	-	5.33	4
A1	0.015	-	0.39	-	4
A2	0.115	0.195	2.93	4.95	-
В	0.014	0.022	0.356	0.558	-
B1	0.045	0.070	1.15	1.77	8, 10
С	0.008	0.014	0.204	0.355	-
D	0.735	0.775	18.66	19.68	5
D1	0.005	-	0.13	-	5
Е	0.300	0.325	7.62	8.25	6
E1	0.240	0.280	6.10	7.11	5
е	0.100 BSC		2.54	BSC	-
e _A	0.300 BSC		7.62	BSC	6
e _B	-	0.430	-	10.92	7
L	0.115	0.150	2.93	3.81	4
N	16		1	6	9

Rev. 0 12/93

Small Outline Plastic Packages (SOIC)



M20.3 (JEDEC MS-013-AC ISSUE C) 20 LEAD WIDE BODY SMALL OUTLINE PLASTIC PACKAGE

	INCHES		MILLIMETERS		
SYMBOL	MIN	MAX	MIN	MAX	NOTES
Α	0.0926	0.1043	2.35	2.65	-
A1	0.0040	0.0118	0.10	0.30	-
В	0.013	0.0200	0.33	0.51	9
С	0.0091	0.0125	0.23	0.32	-
D	0.4961	0.5118	12.60	13.00	3
E	0.2914	0.2992	7.40	7.60	4
е	0.050 BSC		1.27 BSC		-
Н	0.394	0.419	10.00	10.65	-
h	0.010	0.029	0.25	0.75	5
L	0.016	0.050	0.40	1.27	6
N	20		20		7
α	0°	8 ⁰	0°	8 ⁰	-

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NOTES:

- Symbols are defined in the "MO Series Symbol List" in Section 2.2 of Publication Number 95.
- 2. Dimensioning and tolerancing per ANSI Y14.5M-1982.
- Dimension "D" does not include mold flash, protrusions or gate burrs. Mold flash, protrusion and gate burrs shall not exceed 0.15mm (0.006 inch) per side.
- Dimension "E" does not include interlead flash or protrusions. Interlead flash and protrusions shall not exceed 0.25mm (0.010 inch) per side.
- 5. The chamfer on the body is optional. If it is not present, a visual index feature must be located within the crosshatched area.
- 6. "L" is the length of terminal for soldering to a substrate.
- 7. "N" is the number of terminal positions.
- 8. Terminal numbers are shown for reference only.
- The lead width "B", as measured 0.36mm (0.014 inch) or greater above the seating plane, shall not exceed a maximum value of 0.61mm (0.024 inch)
- Controlling dimension: MILLIMETER. Converted inch dimensions are not necessarily exact.

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